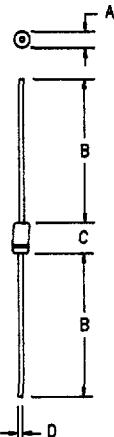


# 1 Amp Schottky Rectifier

## MS108, 109, 110

C



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.081	.107	2.057	2.718	Dia.
B	1.10	---	27.94	---	
C	.160	.205	4.064	5.207	
D	.028	.034	.711	.864	Dia.

### PLASTIC DO41

Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage	• Schottky Barrier Rectifier • Guard Ring Protection • 175°C Junction Temperature • V <sub>RRM</sub> 80 to 100 Volts
MS108	80V	80V	
MS109	90V	90V	
MS110	100V	100V	

#### Electrical Characteristics

Average forward current	I <sub>F(AV)</sub> 1.0 Amps	T <sub>A</sub> = 135°C Square wave, R <sub>θJL</sub> = 50°C/W, L = 0"
Average forward current	I <sub>F(AV)</sub> 1.0 Amps	T <sub>A</sub> = 120°C Square wave, R <sub>θJL</sub> = 68°C/W, L = 3/8"
Maximum surge current	I <sub>FSM</sub> 75 Amps	8.3ms, half sine, T <sub>J</sub> = 175°C
Max peak forward voltage	V <sub>FM</sub> .53 Volts	I <sub>FM</sub> = 0.1A; T <sub>J</sub> = 25°C*
Max peak forward voltage	V <sub>FM</sub> .81 Volts	I <sub>FM</sub> = 1.0A; T <sub>J</sub> = 25°C*
Max peak reverse current	I <sub>RRM</sub> 100 μA	V <sub>RRM</sub> , T <sub>J</sub> = 25°C
Typical junction capacitance	C <sub>J</sub> 45pF	V <sub>R</sub> = 5.0V, T <sub>J</sub> = 25°C

\*Pulse test: Pulse width 300 μsec, Duty cycle 2%

#### Thermal and Mechanical Characteristics

Storage temperature range	T <sub>STG</sub>	-40°C to 175°C
Operating junction temp range	T <sub>J</sub>	-40°C to 175°C
Maximum thermal resistance	R <sub>θJL</sub>	68°C/W Junction to Lead
L = 3/8"	R <sub>θJL</sub>	50°C/W Junction to Lead
L = 0		.011 ounces (0.34 grams) typical
Weight		

# MS108, 109, 110

Figure 1  
Typical Forward Characteristics

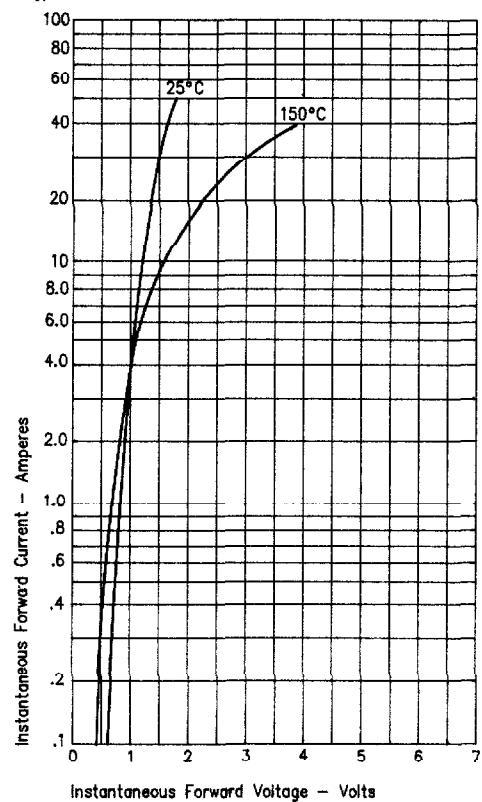


Figure 3  
Typical Junction Capacitance

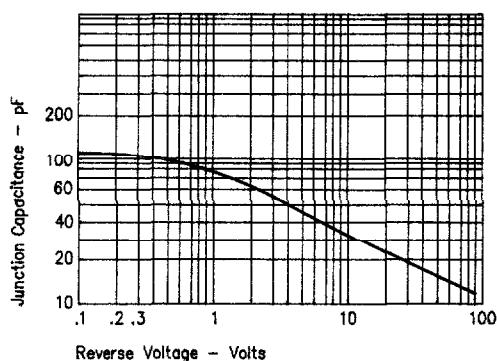


Figure 2  
Typical Reverse Characteristics

